## NSN 5961-00-345-7666

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## **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches Internal Configuration: Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Mounting Method:** Terminal **Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, dc and 1.5 gate to source voltage and 6.0 gate to source cutoff voltage **Current Rating Per Characteristic:** 30.00 nanoamperes reverse gate current with all other terminals short-circuit to source, junction-gate **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0